DS2012SF



Rectifier Diode

DS4548-4.2 April 2006 (LN24541)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- Rectification
- Free-wheel Diode
- DC Motor Control
- Power Supplies
- Welding
- · Battery Chargers

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{DRM} and V _{DRM} V	Conditions
DS2012SF60 DS2012SF59 DS2012SF58 DS2012SF57 DS2012SF56 DS2012SF55	6000 5900 5800 5700 5600 5500	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.

KEY PARAMETERS

V_{RRM}	6000V
I _{F(AV)}	1320A
I _{FSM}	16500A

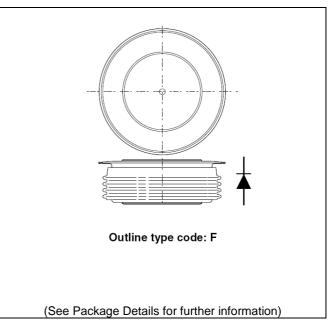


Fig. 1 Package outlines

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table, e.g.:

DS2012SF59

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.



CURRENT RATINGS

T_{case} = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	1320	А			
I _{F(RMS)}	RMS value	-	2073	А			
I _F	Continuous (direct) on-state current	-	1897	А			
Single Sid	Single Side Cooled (Anode side)						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	947	А			
I _{F(RMS)}	RMS value	-	1487	А			
I _F	Continuous (direct) on-state current	-	1283	А			

$T_{case} = 100$ °C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	1015	А			
I _{F(RMS)}	RMS value	-	1594	Α			
I _F	Continuous (direct) on-state current	-	1480	Α			
Single Sic	de Cooled (Anode side)						
I _{F(AV)}	Mean forward current	Half wave resistive load	680	Α			
I _{F(RMS)}	RMS value	-	1067	Α			
I _F	Continuous (direct) on-state current	-	920	А			



SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150℃	13.5	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4}$ sine	0.92	MA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150℃	16.5	kA
l ² t	I ² t for fusing	$V_R = 0$	1.425	MA ² s

THERMAL AND MECHANICAL RATINGS

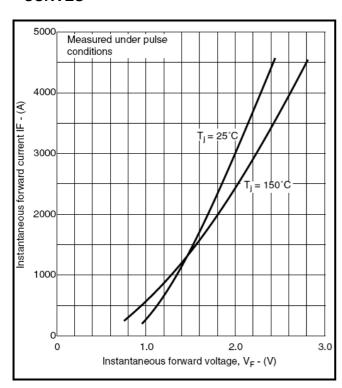
Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.022	€/W
		Single side cooled	Anode DC	-	0.038	€/W
			Cathode DC	-	0.052	C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 19.5kN	Double side	-	0.004	C/W
		(with mounting compound)	Single side	-	0.008	C/W
T_{vj}	Virtual junction temperature	On-state (conducting)		-	160	C
		Reverse (blocking)		-	150	ပ
T _{stg}	Storage temperature range			-55	175	Ĉ
F _m	Clamping force			18.0	22.0	kN



CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 3400A peak, T _{case} = 25℃	-	2.1	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 150℃	-	75	mA
Qs	Total stored charge	$I_F = 2000A$, $dI_{RR}/dt = 3A/\mu s$	-	4500	μC
Irr	Peak reverse recovery current	T _{case} = 150℃, V _R =100V	-	120	А
V _{TO}	Threshold voltage	At T _{vj} = 150℃	-	1.0	V
r _T	Slope resistance	At T _{vj} = 150℃	-	0.42	mΩ

CURVES



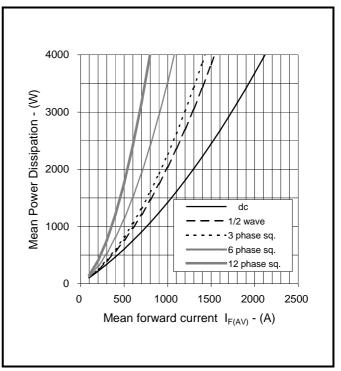


Fig.2 Maximum on-state characteristics

Fig.3 Dissipation curves

 V_{TM} EQUATION

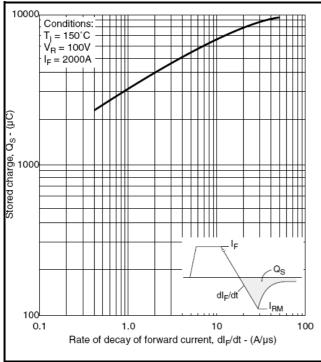
 $V_{TM} = A + Bln (I_T) + C.I_T + D.\sqrt{I_T}$

Where A = 0.819645B = -0.13673

 $C = 5.73 \times 10^{-5}$

D = 0.042435

these values are valid for T_j = 150 $^{\circ}$ C for I $_F$ 500A to 5000A



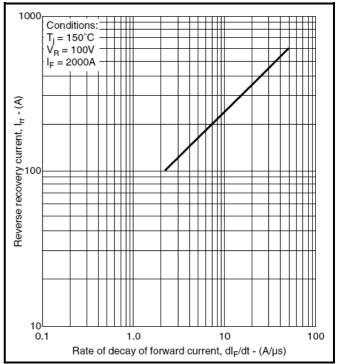
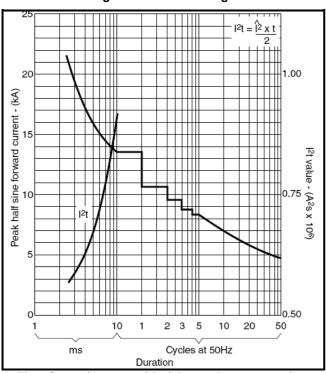
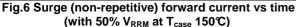


Fig.4 Total stored charge







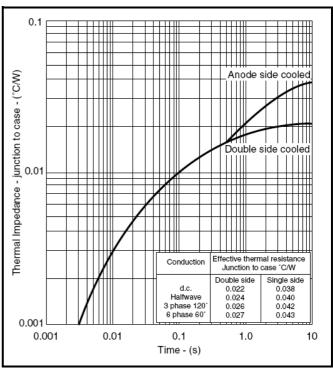
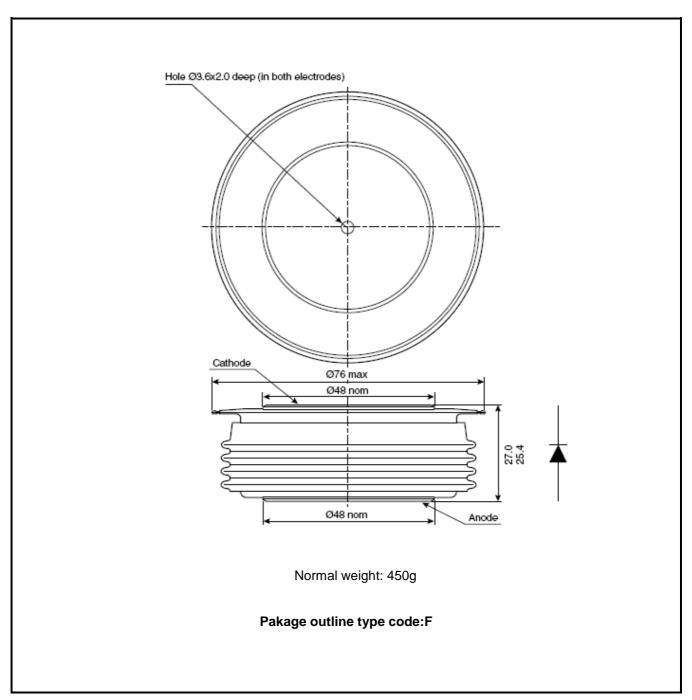


Fig.7 Maximum (limit) transient thermal impedancejunction to case



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.



POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.

Stresses above those listed in this data sheet may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed.



http://www.dynexsemi.com

e-mail: power_solutions@dynexsemi.com

HEADQUARTERS OPERATIONS DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln Lincolnshire, LN6 3LF. United Kingdom.

Fax: +44(0)1522 500550

CUSTOMER SERVICE

Tel: +44(0)1522 502753 / 502901. Fax: +44(0)1522 500020

© Dynex Semiconductor 2003 TECHNICAL DOCUMENTATION - NOT FOR RESALE. PRODUCED IN UNITED KINGDOM.

This publication is issued to provide information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. The Company reserves the right to alter without prior notice the specification, design or price of any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to the Company's conditions of sale, which are available on request

All brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners